BAL-NRF02D3



50 ohm nominal input / conjugate match balun to nRF51822-CEAA/CDAB/CFAC and nRF51422-CEAA/CDAB/CFAC

Datasheet - production data

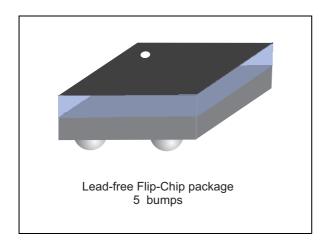
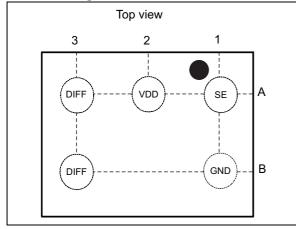


Figure 1. Pin coordinates



Features

- 50 Ω nominal input / conjugate match to Nordic Semiconductor chips nRF51422-CEAA, nRF51422-CDAB, nRF51422-CFAC and nRF51822-CEAA, nRF51822-CDAB, nRF51822-CFAC
- Low insertion loss
- Low amplitude imbalance
- Low phase imbalance
- Small footprint: < 1.2 mm²

Benefits

- Very low profile: < 560 µm after reflow
- High RF performance
- RF BOM and area reduction

Applications

- · 2.45 GHz impedance matched balun filter
- Optimized for Nordic's chip set nRF51422-CEAA, nRF51422-CDAB, nRF51422-CFAC and nRF51822-CEAA, nRF51822-CDAB, nRF51822-CFAC

Description

STMicroelectronics BAL-NRF02D3 is an ultraminiature balun. The BAL-NRF02D3 integrates matching network and harmonics filter. Matching impedance has been customized for the following Nordic Semiconductor circuits: nRF51422-CEAA, nRF51422-CDAB, nRF51822-CDAB, nRF51822-CDAB, nRF51822-CFAC.

The BAL-NRF02D3 uses STMicroelectronics IPD technology on non-conductive glass substrate which optimize RF performances.

The BAL-NRF02D3 has been tested and approved by Nordic Semiconductor in the nRFgo modules.

Application BAL-NRF02D3

1 Application

Figure 2. Application schematic 12pF ⊒16MHz C2 12pF C8 100nF VCC_nRF P0.00 P0.01 P0.02 P0.03 P0.04 P0.05 P0.04 P0.05 P0.06 P0.07 VDD 66 P0.07 1.0nF NRF51822

NRF518 VCC_nRF P0.30 P0.31 P0.00 P0.01 P0.02 P0.03 P0.04 P0.05 P0.06 P0.07 C7 В1 100nF A1RF ANT2 ANT1 B1 VDD_PAGND P0.20 P0.19 P0.18 P0.17 BAL-NRF02D3 VCC_nRF C11_ 100nF C10 =C3 2.2nF 47nF U1 nRF51822-CEAA

BAL-NRF02D3 Characteristics

2 Characteristics

Table 1. Absolute maximum ratings (limiting values)

Symbol	Parameter	Value			Unit	
	Farameter		Тур.	Max.	Onit	
P _{IN}	Input Power RFIN		-	20	dBm	
	ESD ratings human body model (JESD22-A114-C), all I/O one at a time while others connected to GND	2000	-			
V _{ESD}	ESD ratings charge device model (JESD22-C101-C)	500	-		V	
	ESD ratings machine model, all I/O	200	-			
T _{OP}	Operating temperature (JESD22-A115-C), all I/O	-40	-	+105	°C	

Table 2. Impedances ($T_{amb} = 25 \, ^{\circ}C$)

Symbol	Parameter	Value			
Symbol	r al allietei	Min.	Тур.	Max.	Unit
Z _{OUT}	Nominal differential output impedance		matched	-	Ω
Z _{IN}	Z _{IN} Nominal input impedance		50	-	Ω

Table 3. RF performance (T_{amb} = 25 °C)

Symbol	Parameter	Test condition	Value			Unit
	rai ametei	rest condition	Min.	Тур.	Max.	Oilit
F	Frequency range (bandwidth)		2400		2540	MHz
IL	Insertion loss in bandwidth			1.9		dB
R _L	Return loss in bandwidth			12		dB
фimb	Phase imbalance			6		0
Aimb	Amplitude imbalance			0.15		dB
2f0	2nd harmonic S21 attenuation	4880 MHz		10		dB
3f0	3rd harmonic S21 attenuation	7320 MHz		20		dB

Characteristics **BAL-NRF02D3**

2.1 **On-board measurements**

Figure 4. Insertion loss (T_{amb} = 25 °C)

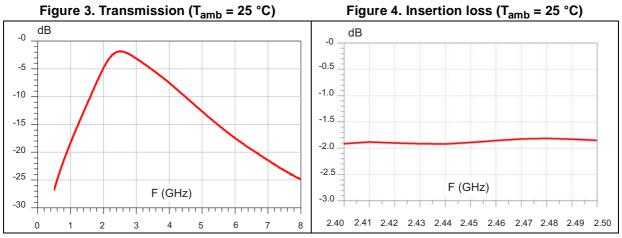


Figure 5. Return loss on SE port $(T_{amb} = 25 °C)$

Figure 6. Return loss on DIFF port $(T_{amb} = 25 °C)$

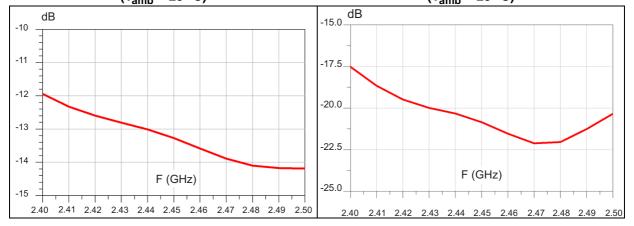
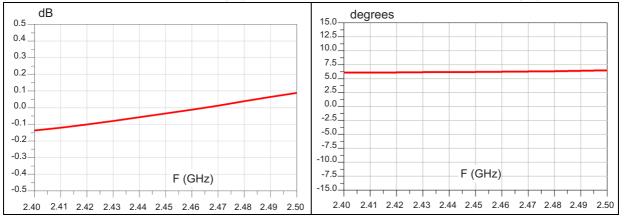


Figure 7. Amplitude imbalance ($T_{amb} = 25$ °C)

Figure 8. Phase imbalance ($T_{amb} = 25 \, ^{\circ}C$)



BAL-NRF02D3 Characteristics

Table 4. Compatibility matrix (nRF51422)

nRF51422 IC revision	Packet/variant	Build code
1	CEAA	A0A
2	CEAA	Bx0
	CDAB	Ax0
3	CEAA	Cx0
	CFAC	Ax0

Table 5. Compatibility matrix (nRF51822)

nRF51822 IC revision	Packet/variant	Build code
1	CEAA	ВА
'	CEAA	В0
	CEAA	CA0
2	CEAA	DA0
	CEAA	Dx0
	CDAB	Ax0
3	CEAA	Ex0
	CFAC	Ax0

Package information BAL-NRF02D3

3 Package information

- Epoxy meets UL94, V0
- Lead-free package

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: www.st.com. ECOPACK[®] is an ST trademark.

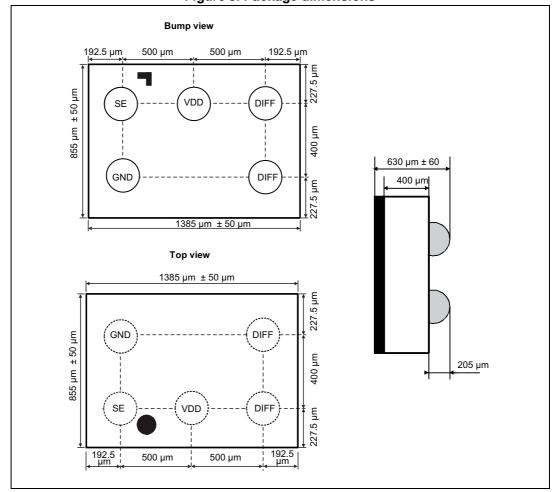


Figure 9. Package dimensions

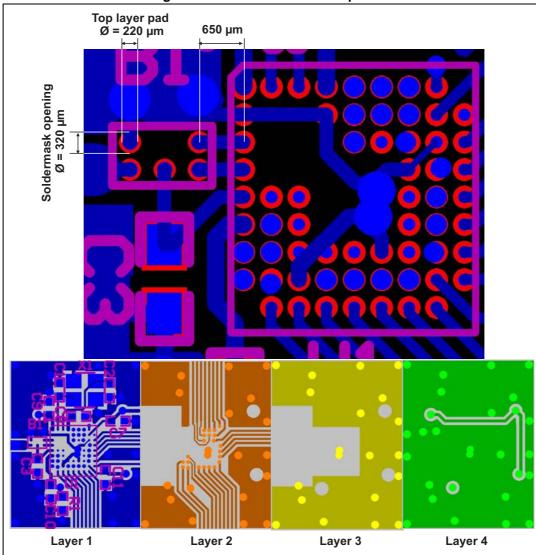
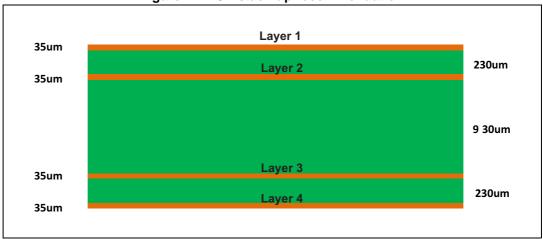


Figure 10. Recommended land pattern





Package information BAL-NRF02D3

Figure 12. Marking

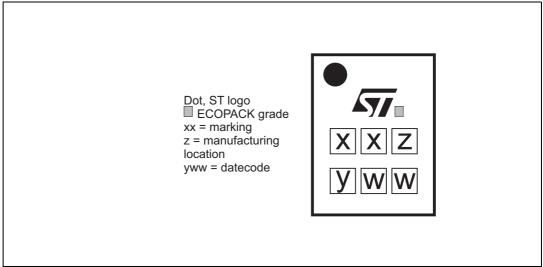
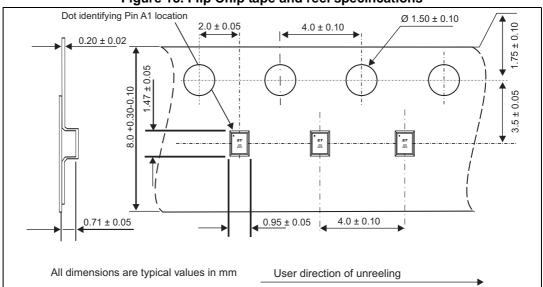


Figure 13. Flip Chip tape and reel specifications

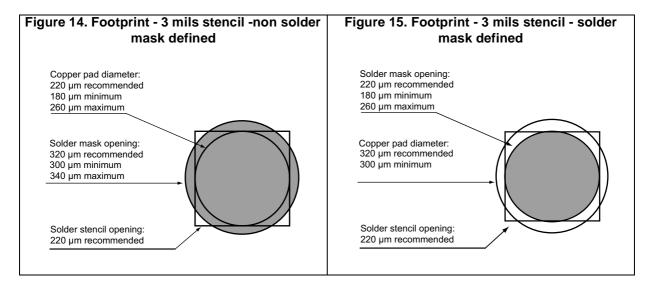


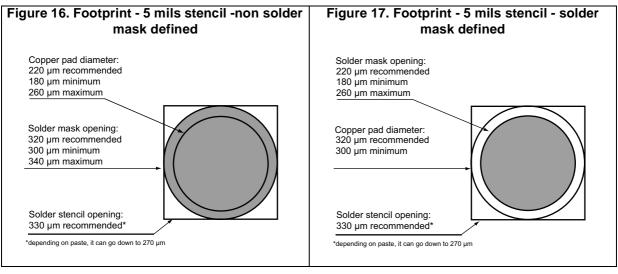
Note: More information is available in the STMicroelectronics Application notes:

AN2348 Flip-Chip: "Package description and recommendations for use"

AN4315: "BAL-NRF02D3 matched balun with integrated harmonics filter for Nordic Semiconductor ultralow power transceivers"

BAL-NRF02D3 Package information





Ordering information BAL-NRF02D3

4 Ordering information

Table 6. Ordering information

Order code	Marking	Weight	Base Qty	Delivery mode
BAL-NRF02D3	SK	1.58 mg	5000	Tape and Reel

5 Revision history

Table 7. Document revision history

Date	Revision	Changes
02-Jul-2013	1	Initial release
30-Aug-2013	2	Updated Table 1.
13-Oct-2014	3	Updated Figure 9.
25-Mar-2015	4	Updated cover page, added Table 4 and Table 5.
15-Jun-2015	5	Updated Table 1.

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